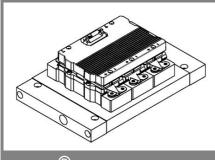
## SKiiP 1803GB122-3DW



SKiiP<sup>®</sup> 3

2-pack-integrated intelligent Power System

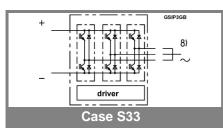
#### **Power section**

SKiiP 1803GB122-3DW

Data

#### **Power section features**

- SKiiP technology inside
- SPT (Soft Punch Through) IGBTs
- CAL diode technology
- Integrated current sensor
- Integrated temperature sensor
- Integrated heat sink
- IEC 60721-3-3 (humidity) class 3K3/IE32 (SKiiP<sup>®</sup> 3 System)
- IEC 60068-1 (climate) 40/125/56
- UL recognized File no. E63532
- with assembly of suitable MKP capacitor per terminal
- AC connection busbars must be connected by the user; copper busbars available on request

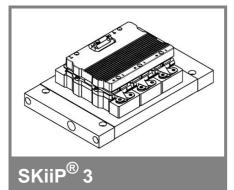


Absolute	e Maximum Ratings	$T_s = 25^{\circ}C$ unless otherwise specified				
Symbol	Conditions	Values	Units			
IGBT						
V <sub>CES</sub>		1200	V			
V <sub>CC</sub> <sup>1)</sup>	Operating DC link voltage	900	V			
V <sub>GES</sub>		± 20	V			
I <sub>C</sub>	T <sub>s</sub> = 25 (70) °C	1800 (1350)	А			
Inverse diode						
I <sub>F</sub> = - I <sub>C</sub>	T <sub>s</sub> = 25 (70) °C	1460 (1110)	А			
I <sub>FSM</sub>	T <sub>j</sub> = 150 °C, t <sub>p</sub> = 10 ms; sin	10200	А			
I²t (Diode)	Diode, T <sub>j</sub> = 150 °C, 10 ms	520	kA²s			
T <sub>j</sub> , (T <sub>stg</sub> )		- 40 + 150 (125)	°C			
V <sub>isol</sub>	rms, AC, 1 min, main terminals to heat sink	3000	V			
I <sub>AC-terminal</sub>	per AC terminal, rms, T <sub>s</sub> = 70 °C,	400	А			
	T <sub>terminal</sub> <115 °C					

Characte	Characteristics				T <sub>s</sub> = 25°	°C unless o	otherwise	specified
Symbol	Conditions			min.	typ.	max.	Units	
IGBT								
V <sub>CEsat</sub>	I <sub>C</sub> = 900 A, measured at ter	T <sub>j</sub> = 25 (* minal	125) °C;			2,3 (2,5)	2,6	V
V <sub>CEO</sub>	T <sub>j</sub> = 25 (125					1,1 (1)	1,3 (1,2)	V
r <sub>CE</sub>	$T_j = 25 (125) °C;$ at terminal				1,3 (1,7)	1,5 (1,9)	mΩ	
I <sub>CES</sub>	V <sub>GE</sub> = 0 V, V <sub>CE</sub> = V <sub>CES</sub> , T <sub>i</sub> = 25 (125) °C			3,6 (108)			mA	
$E_{on} + E_{off}$	I <sub>C</sub> = 900 A,	V <sub>CC</sub> = 60	00 V			270		mJ
	T <sub>j</sub> = 125 °C,	V <sub>CC</sub> = 9	00 V			476		mJ
R <sub>CC+EE</sub> '	terminal chi	p, T <sub>j</sub> = 25	5 °C		0,17			mΩ
$L_{CE}$	top, bottom					4		nH
C <sub>CHC</sub>	per phase, A	AC-side				3		nF
Inverse o								
V <sub>F</sub> = V <sub>EC</sub>	I <sub>F</sub> = 900 A, <sup>-</sup> measured at ter	T <sub>j</sub> = 25 (1 minal	125) °C			1,95 (1,7)	2,1	V
V <sub>TO</sub>	T <sub>i</sub> = 25 (125	5) °C				1,1 (0,8)	1,2 (0,9)	V
r <sub>T</sub>	$T_{i} = 25 (125)$	) °C				0,9 (1)	1 (1,2)	mΩ
E <sub>rr</sub>	I <sub>C</sub> = 900 A,	$V_{\rm CC} = 60$	00 V			72		mJ
	T <sub>j</sub> = 125 °C,	V <sub>CC</sub> = 9	00 V			92		mJ
Mechani	cal data							
M <sub>dc</sub>	DC terminals, SI Units				6		8	Nm
M <sub>ac</sub>	AC terminals, SI Units			13		15	Nm	
w	SKiiP <sup>®</sup> 3 System w/o heat sink					2,4		kg
w	heat sink					5,2		kg
	character							
		το bui	lit-in tem	perature	e sensor	(acc.iec		
R <sub>th(j-s)I</sub>	per IGBT						0,017	K/W
R <sub>th(j-s)D</sub>	per diode						0,033	K/W
Z <sub>th</sub>	R <sub>i</sub> (mK/W) (max. values) 1 2 3 4			tau <sub>i</sub> (s)   1 2 3			4	
7	1,4	∠ 6,8	3 7,8	4	69	∠ 0,35	0.02	4
Z <sub>th(j-r)I</sub> Z <sub>th(j-r)D</sub>	2,6	4	7,0 17,7	17,7	50	5	0,02	0,04
	4,6	4,7	1,1	0,6	48	15	2,8	0,4
Z <sub>th(r-a)</sub>	.,0	т, г	1,1	0,0	70	10	2,0	0,7

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# SKiiP 1803GB122-3DW



### 2-pack-integrated intelligent Power System

2-pack integrated gate driver SKiiP 1803GB122-3DW

Data

### Gate driver features

- CMOS compatible inputs
- Wide range power supply
- Integrated circuitry to sense phase current, heat sink temperature and DC-bus voltage (option)
- Short circuit protection
- Over current protection
- Over voltage protection (option)
- Power supply protected against under voltage
- Interlock of top/bottom switch
- Isolation by transformers
- Fibre optic interface (option for GB-types only)
- IEC 60068-1 (climate) 40/85/56
- UL recognized file no. 242581

Absolute Maximum Ratings		$a = 25^{\circ}$ C unless otherwise specified		
Symbol	Conditions	Values	Units	
V <sub>S2</sub>	unstabilized 24 V power supply	30	V	
V <sub>i</sub>	input signal voltage (high)	15 + 0,3	V	
dv/dt	secondary to primary side	75	kV/μs	
V <sub>isollO</sub>	input / output (AC, rms, 2s)	3000	V	
VisoIPD	partial discharge extinction voltage, rms, $Q_{PD} \leq 10 \text{ pC}$ ;	1170	V	
V <sub>isol12</sub>	output 1 / output 2 (AC, rms, 2s)	1500	V	
f <sub>sw</sub>	switching frequency	10	kHz	
f <sub>out</sub>	output frequency for I <sub>peak(1)</sub> =I <sub>C</sub>	10	kHz	
$T_{op} (T_{stg})$	operating / storage temperature	- 40 + 85	°C	

Characte	eristics	(T <sub>a</sub>			= 25°C)
Symbol	Conditions	min.	typ.	max.	Units
V <sub>S2</sub>	supply voltage non stabilized	13	24	30	V
I <sub>S2</sub>	V <sub>S2</sub> = 24 V	278+29*f/kHz+0,00015*(I <sub>AC</sub> /A) <sup>2</sup>			mA
V <sub>iT+</sub>	input threshold voltage (High)			12,3	V
V <sub>iT-</sub>	input threshold voltage (Low)	4,6			V
R <sub>IN</sub>	input resistance		10		kΩ
CIN	input capacitance		1		nF
t <sub>d(on)IO</sub>	input-output turn-on propagation time		1,3		μs
t <sub>d(off)IO</sub>	input-output turn-off propagation time		1,3		μs
t <sub>pERRRESET</sub>	error memory reset time		9		μs
t <sub>TD</sub>	top / bottom switch interlock time		3,3		μs
I <sub>analogOUT</sub>	max. 5mA; 8 V corresponds to 15 V supply voltage for external components		1500		A
I <sub>s1out</sub>	max. load current			50	mA
I <sub>TRIPSC</sub>	over current trip level				
	$(I_{analog} OUT = 10 V)$		1875		A
T <sub>tp</sub>	over temperature protection	110		120	°C
U <sub>DCTRIP</sub>	U <sub>DC</sub> -protection ( U <sub>analog OUT</sub> = 9 V);	i	not implemente	d	V
	(option for GB types)				

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